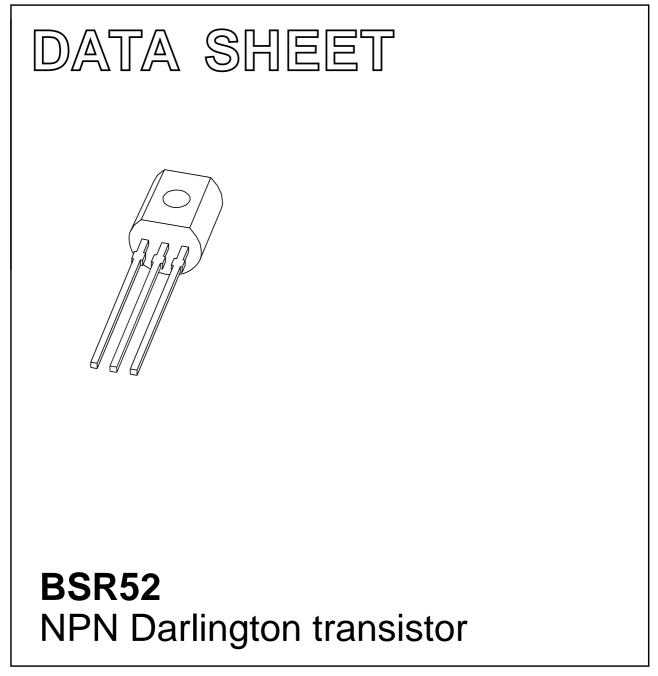
DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1999 Apr 26 2004 Nov 11



FEATURES

- High current (max. 1 A)
- Low voltage (max. 80 V)
- Integrated diode and resistor.

APPLICATIONS

• Industrial high gain amplification.

DESCRIPTION

NPN Darlington transistor in a TO-92; SOT54 plastic package. PNP complement: BSR62.

PINNING

PIN	DESCRIPTION	
1	base	
2	collector	
3	emitter	

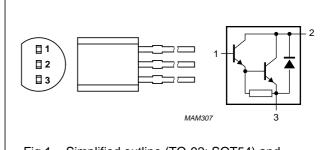


Fig.1 Simplified outline (TO-92; SOT54) and symbol.

ORDERING INFORMATION

		PACKAGE			
	NAME	DESCRIPTION	VERSION		
BSR52	SC-43A	3A plastic single-ended leaded (through hole) package; 3 leads			

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	90	V
V _{CES}	collector-emitter voltage	V _{BE} = 0 V	-	80	V
V _{EBO}	emitter-base voltage	open collector	_	5	V
I _C	collector current (DC)		_	1	А
I _{CM}	peak collector current		_	2	А
I _B	base current (DC)		_	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	830	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

BSR52

BSR52

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT	
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	150	K/W	

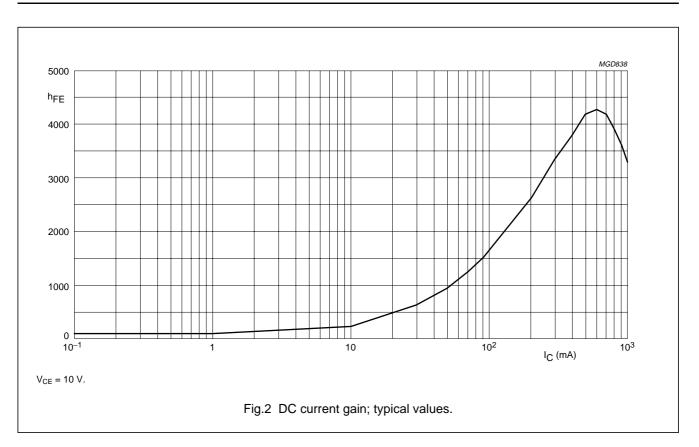
Note

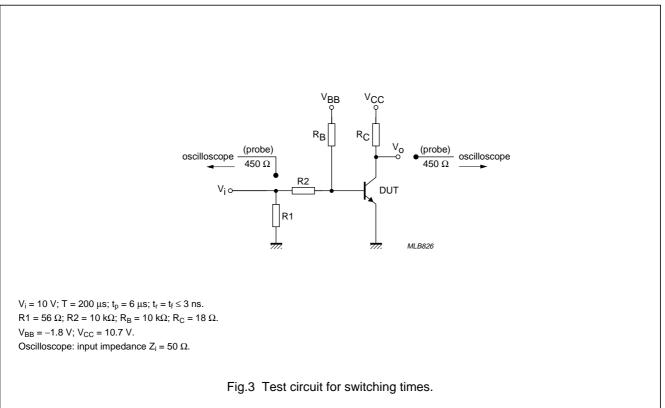
1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

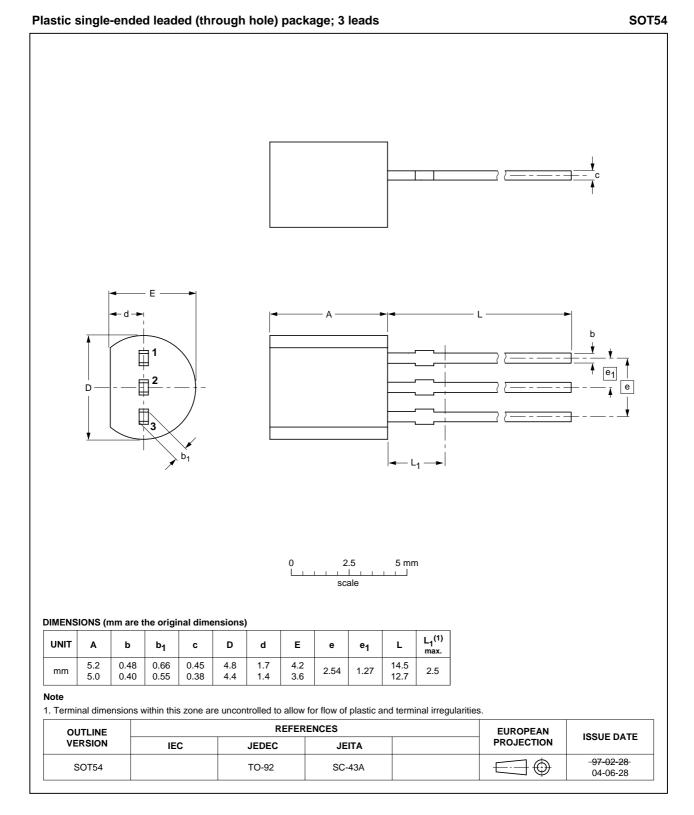
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CES}	collector-base cut-off current	V _{BE} = 0 V; V _{CE} = 80 V	_	-	50	nA
I _{EBO}	emitter-base cut-off current	$V_{EB} = 4 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	-	-	50	nA
h _{FE}	DC current gain	V _{CE} = 10 V; see Fig.2				
		I _C = 150 mA	1000	-	-	
		I _C = 500 mA	2000	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_{C} = 0.5 \text{ A}; I_{B} = 0.5 \text{ mA}$	-	-	1.3	V
		$I_{\rm C} = 1 \text{ A}; I_{\rm B} = 4 \text{ mA}$	-	-	1.6	V
V _{BEsat}	base-emitter saturation voltage	I _C = 0.5 A; I _B = 0.5 mA	-	-	1.9	V
		I _C = 1 A; I _B = 4 mA	-	-	2.2	V
f _T	transition frequency	$V_{CE} = 5 \text{ V}; I_{C} = 500 \text{ mA};$ f = 100 MHz	-	200	-	MHz
Switching times (between 10% and 90% levels); see Fig.3						
t _{on}	turn-on time	I _{Con} = 500 mA; I _{Bon} = 0.5 mA;	-	-	500	ns
t _{off}	turn-off time	$I_{Boff} = -0.5 \text{ mA}$	-	-	1300	ns





BSR52

PACKAGE OUTLINE



BSR52

2004 Nov 11

5

BSR52

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
1	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
11	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

Notes

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- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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